

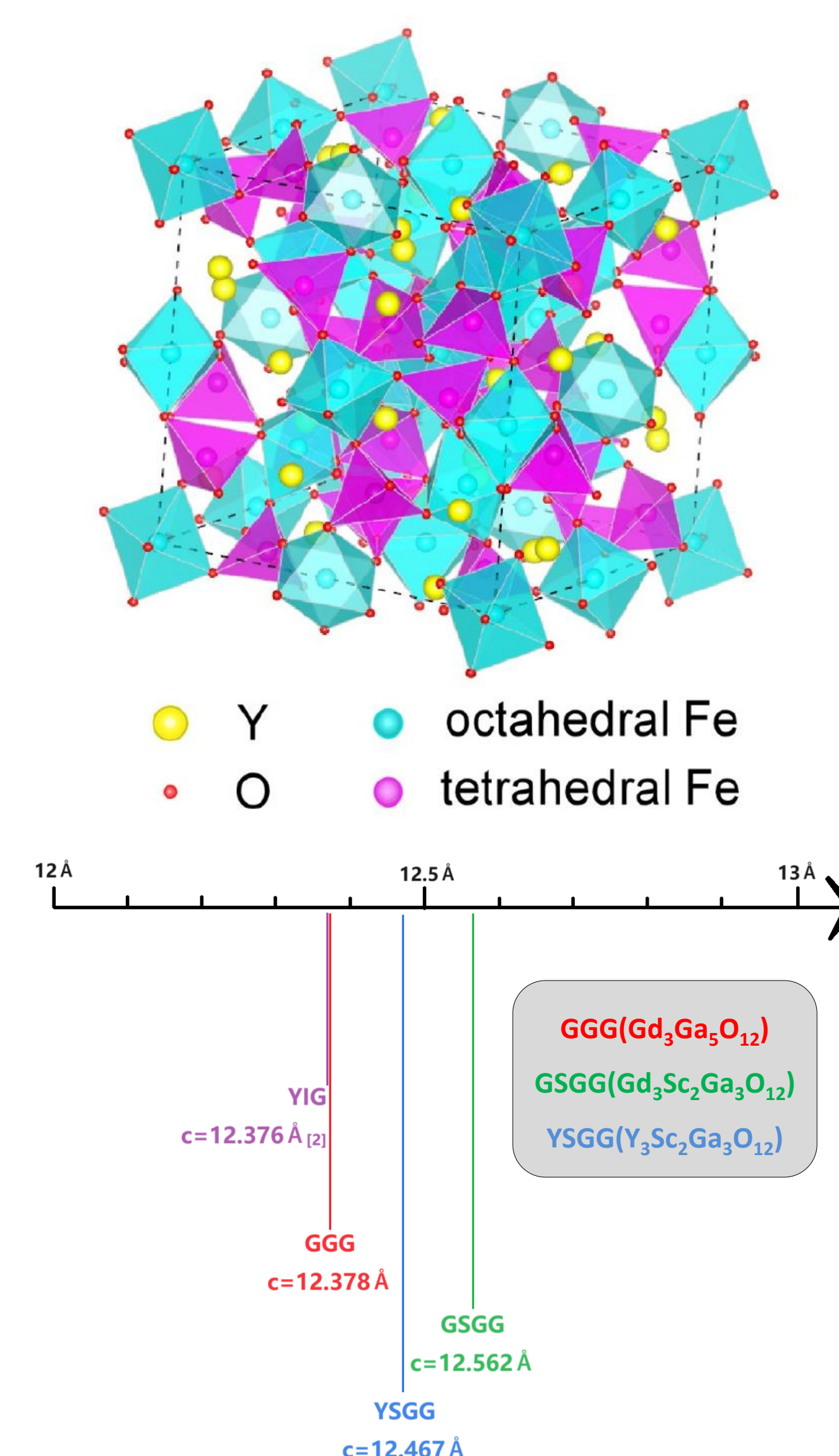
Growth and Characterization of $\text{Y}_3\text{Fe}_5\text{O}_{12}$ Thin Films

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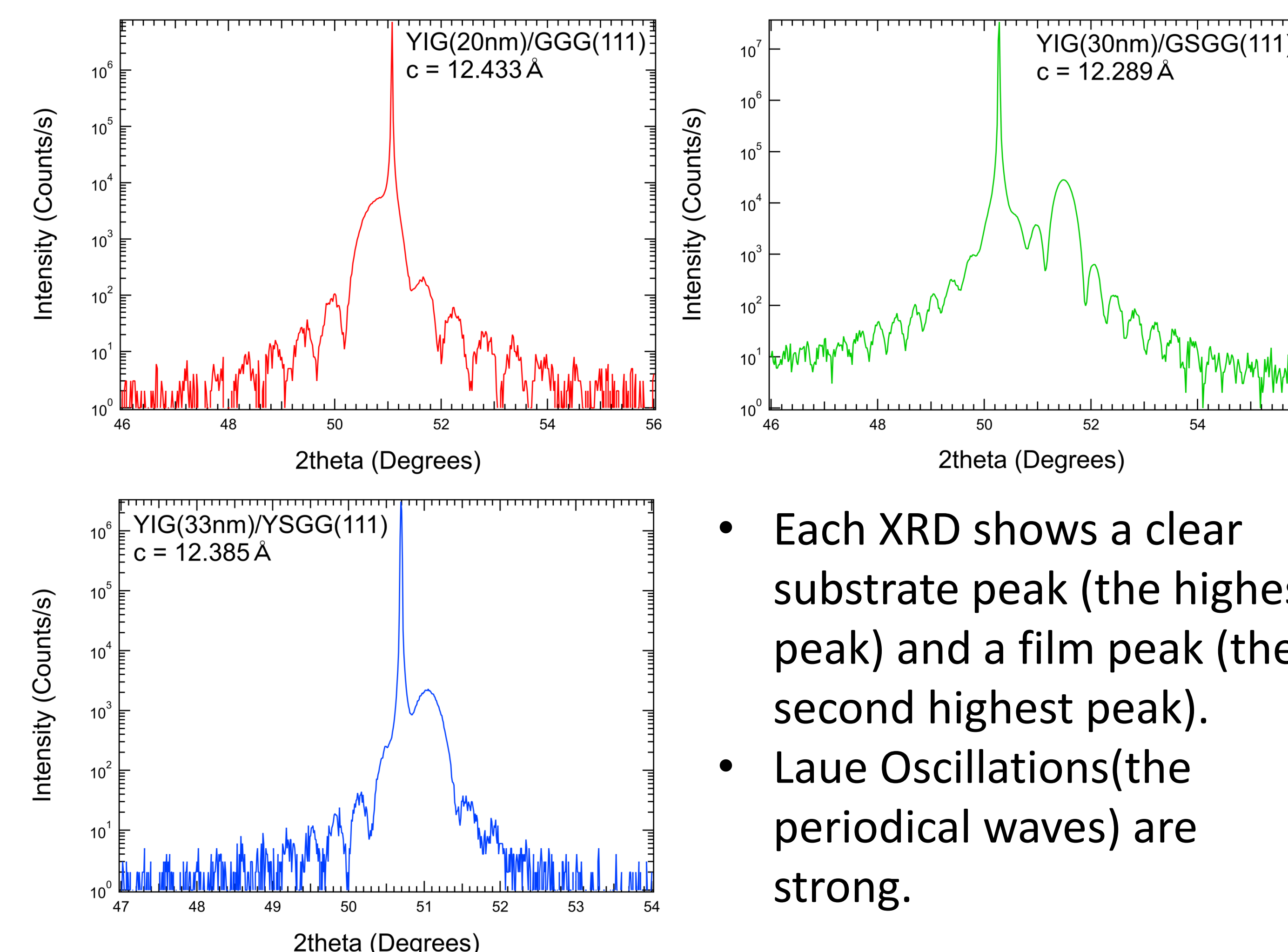
Introduction

- $\text{Y}_3\text{Fe}_5\text{O}_{12}$ (Yttrium Iron Garnet, YIG) is a ferrimagnetic insulator with outstanding low magnetic damping.
- Due to these properties, YIG is an ideal material for magnon transport [1].
- We grow YIG thin films down to the scale of nanometers on three different substrates (GGG, GSGG, and YSGG) using off-axis sputtering.
- X-ray diffraction (XRD) measurement, vibrating sample magnetometer (VSM), and ferromagnetic resonance (FMR) measurement are used to characterize the quality of the films.



Crystal Structure

XRD

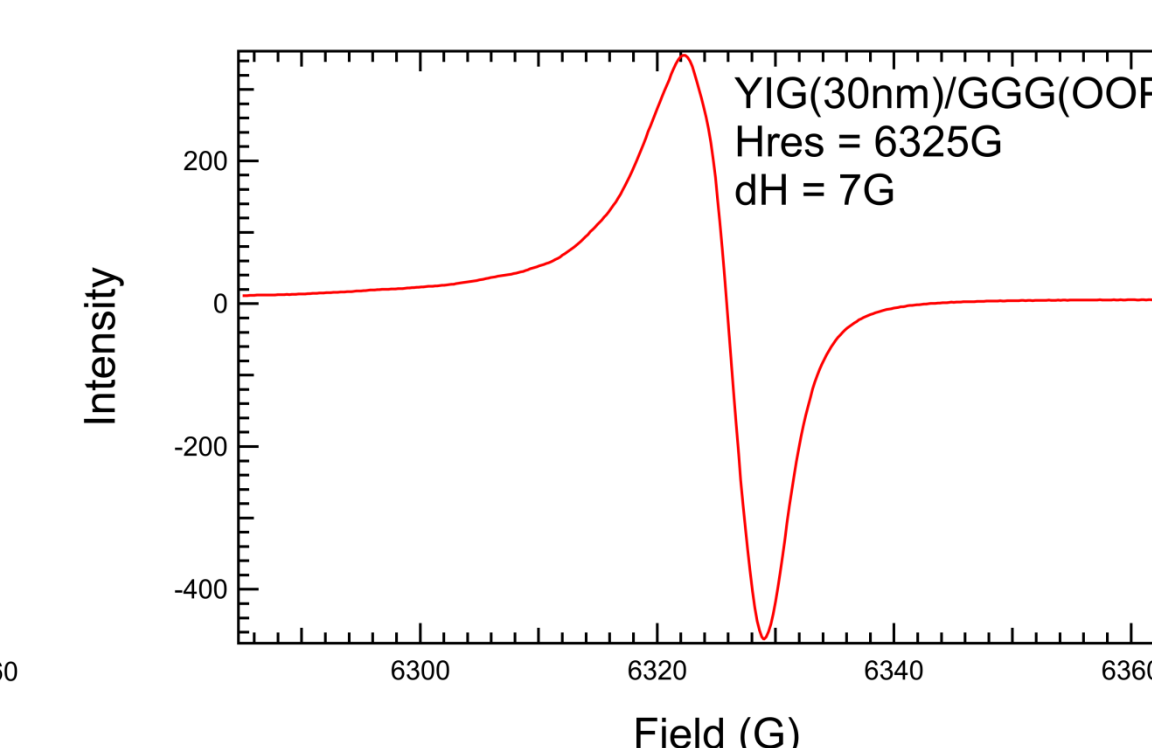
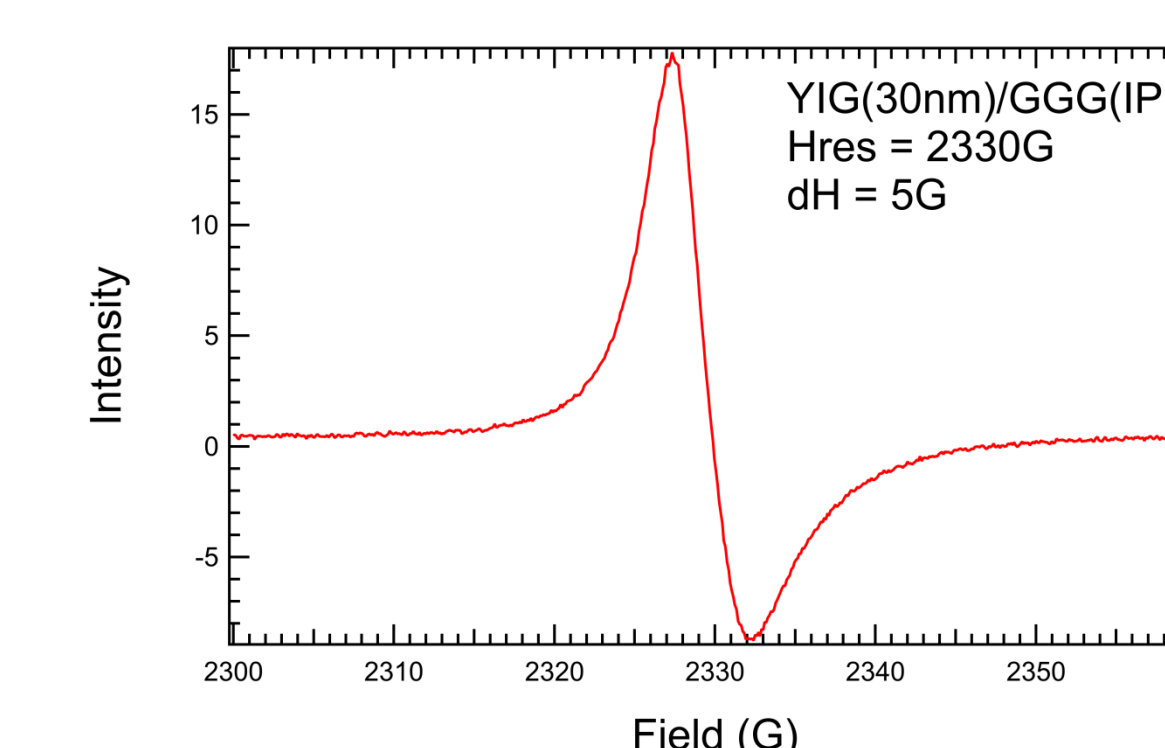


FMR Measurements

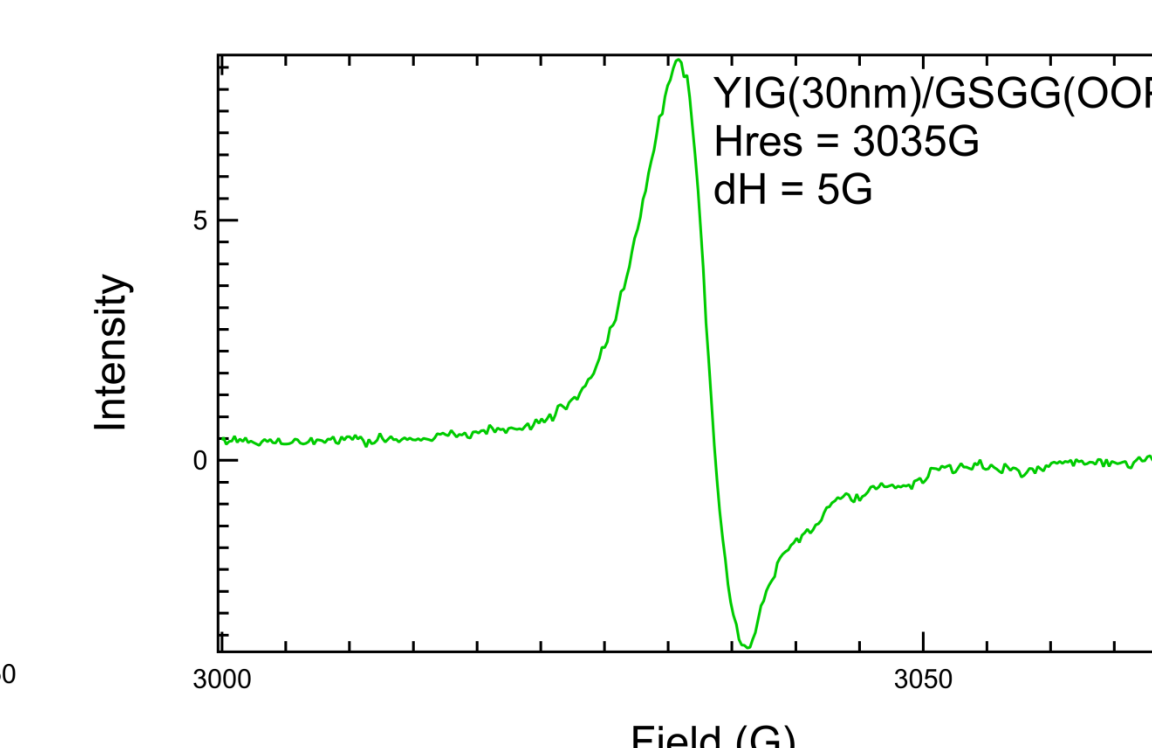
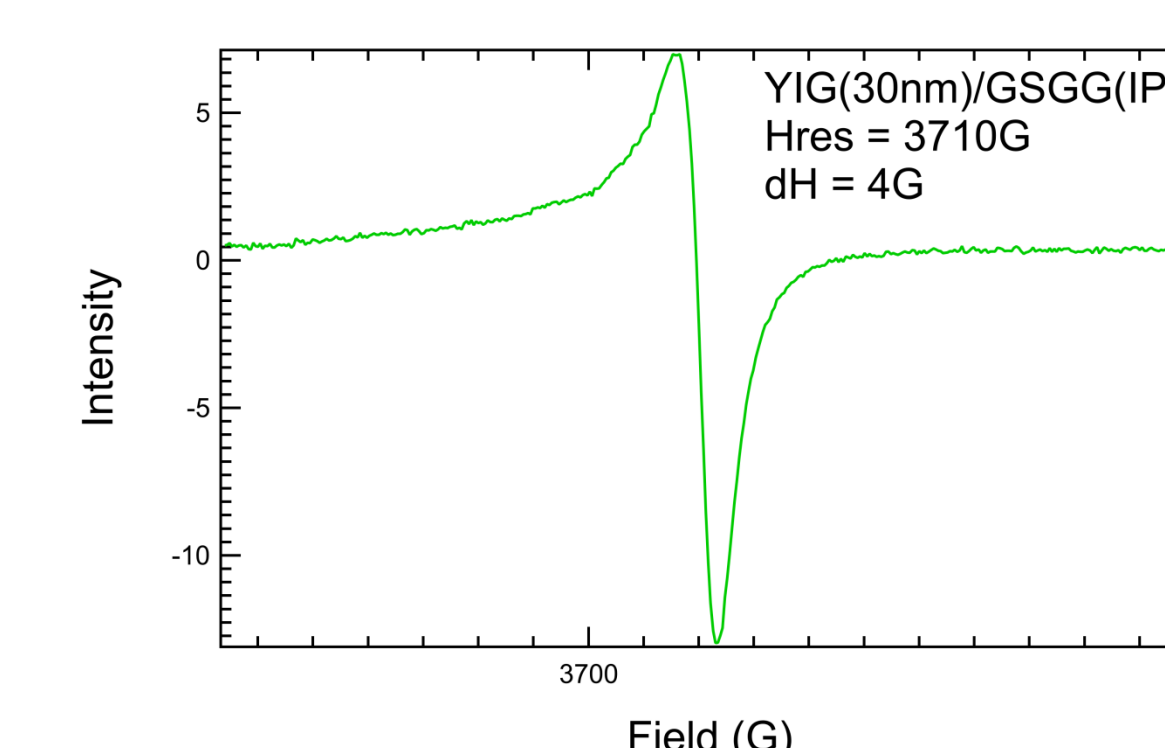
In plane(IP)

Out of plane(OOP)

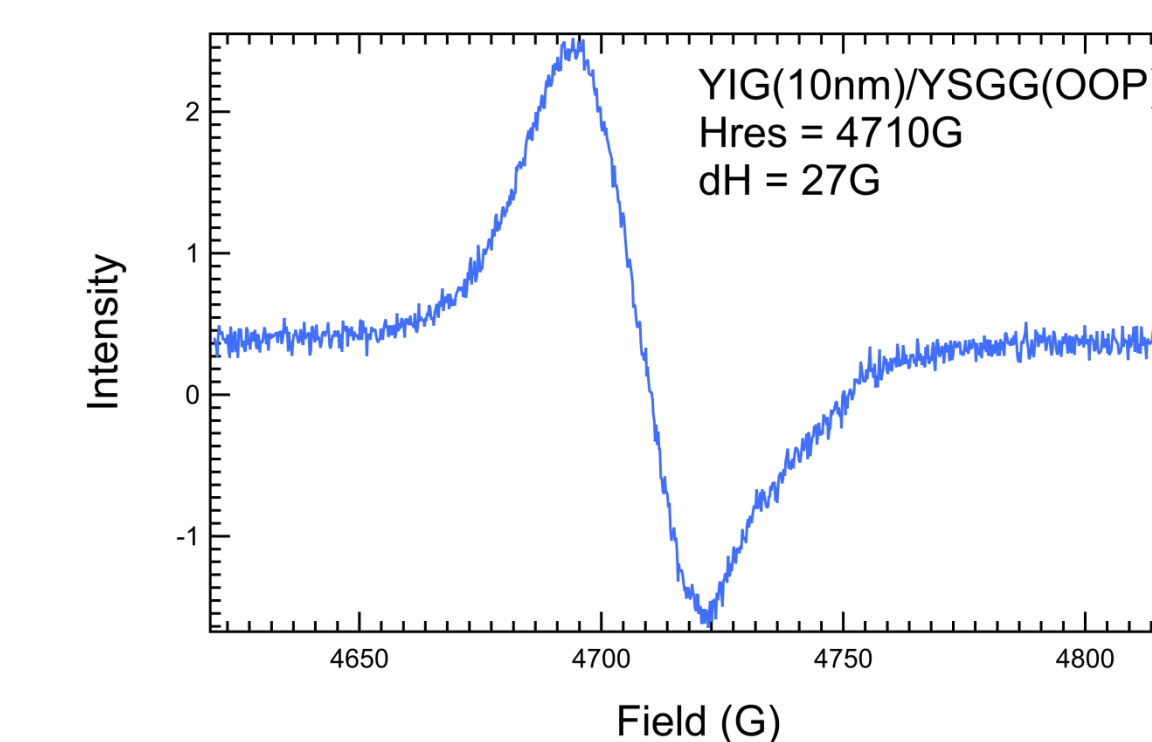
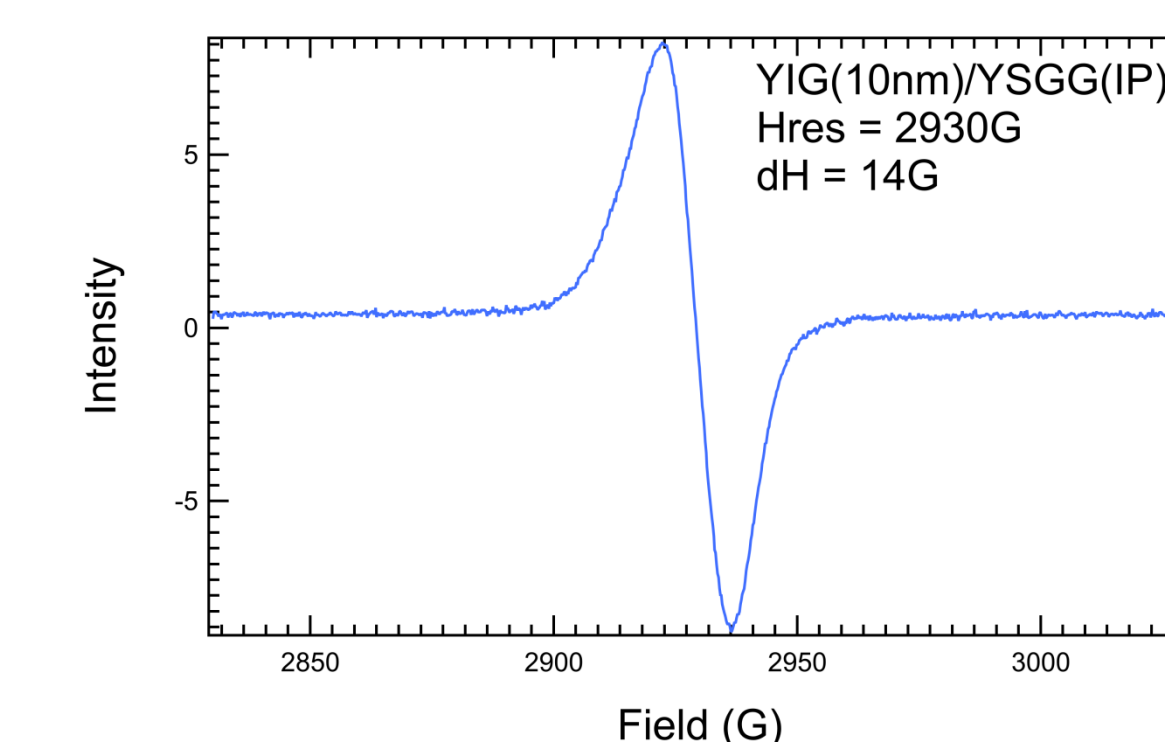
YIG/GGG



YIG/GSGG



YIG/YSGG



- Expressed in the first derivative of the microwave absorption, the symmetry and low peak-to-peak line width confirm high quality YIG films.

Conclusion

- Using off-axis sputtering, we are able to grow high quality YIG films, evidenced by XRD, VSM, and FMR measurements.

Future Works

- We will make Platinum device on the top of the YIG layer we grew to test magnon transport properties of YIG.

References

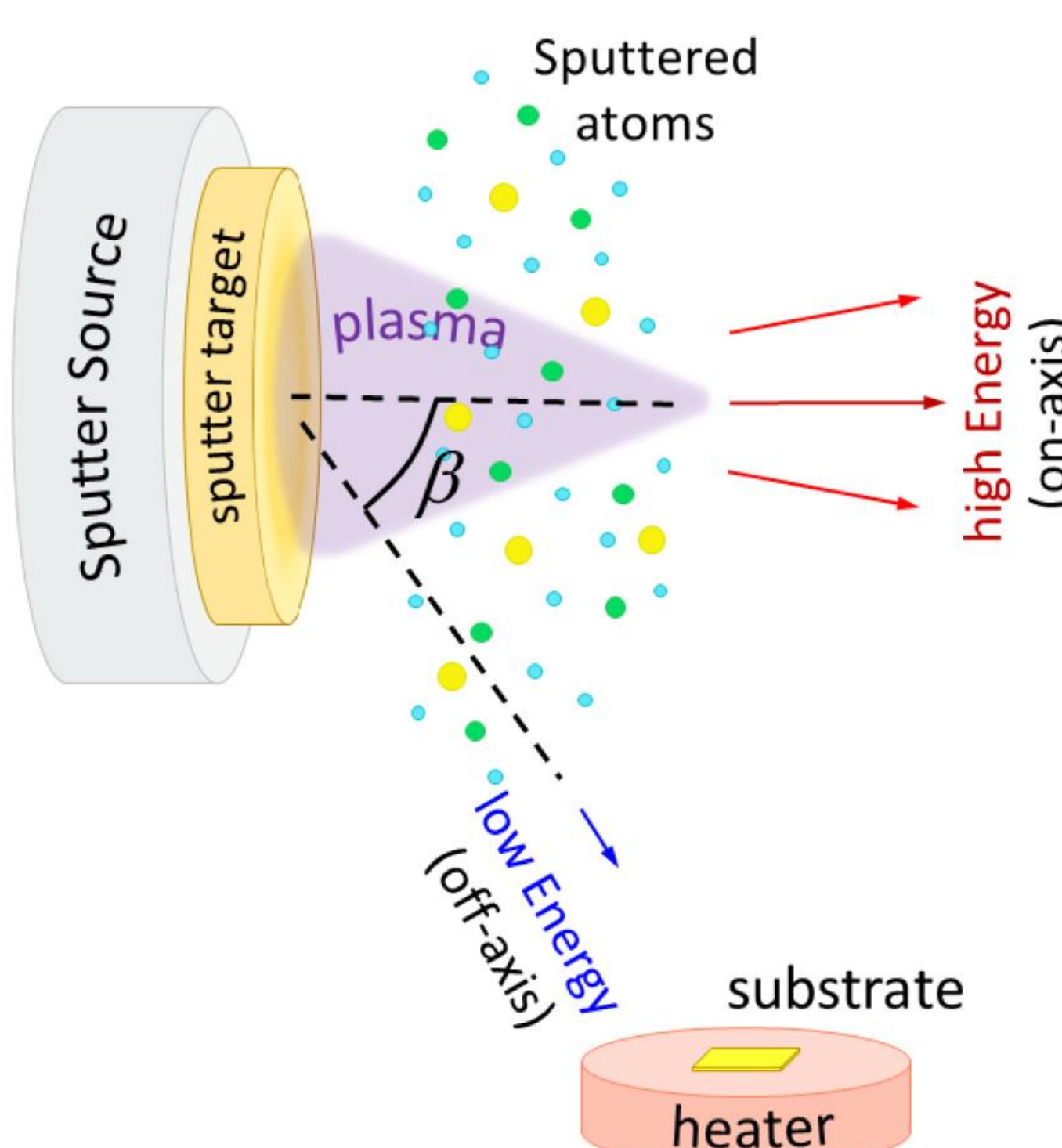
- [1] Wei, XY., Santos, O.A., Lusero, C.H.S. et al. Giant magnon spin conductivity in ultrathin yttrium iron garnet films. Nat. Mater. 21, 1352–1356 (2022). <https://doi.org/10.1038/s41563-022-01369-0>
- [2] Wu, M. (2010). Nonlinear Spin Waves in Magnetic Film Feedback Rings. Solid State Physics - Advances in Research and Applications, 62, 163–224. <https://doi.org/10.1016/B978-0-12-374293-3.00003-1>

Acknowledgement

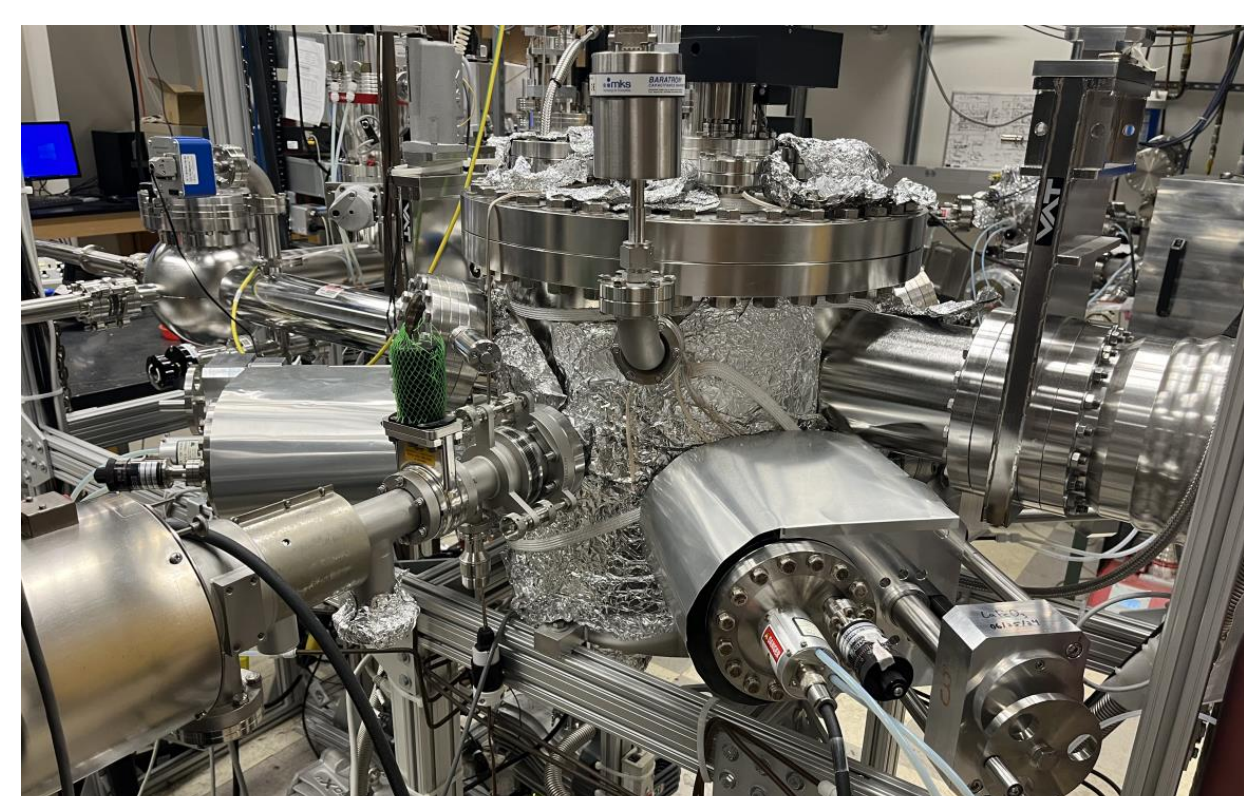
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Off-axis Sputtering



- Films are grown using off-axis sputtering.
- Off-axis sputtering has the advantage of using lower energy ions, reducing the damage in the film due to bombardment.
- A low growth pressure of 11.5 mTorr allows us to ensure good cation stoichiometry of our films.
- We heat the substrate to 650°C to give ions enough mobility to epitaxially order.
- We grow in Ar + 1%O₂ environment to minimize any oxygen vacancies.



Magnetization

VSM

